

TRANSITION-MODE PFC CONTROLLER

1 Features

- REALISED IN BCD TECHNOLOGY
- TRANSITION-MODE CONTROL OF PFC PRE-REGULATORS
- PROPRIETARY MULTIPLIER DESIGN FOR MINIMUM THD OF AC INPUT CURRENT
- VERY PRECISE ADJUSTABLE OUTPUT OVERVOLTAGE PROTECTION
- ULTRA-LOW ($\leq 70\mu\text{A}$) START-UP CURRENT
- LOW ($\leq 4\text{ mA}$) QUIESCENT CURRENT
- EXTENDED IC SUPPLY VOLTAGE RANGE
- ON-CHIP FILTER ON CURRENT SENSE
- DISABLE FUNCTION
- 1% (@ $T_j = 25^\circ\text{C}$) INTERNAL REFERENCE VOLTAGE
- -600/+800mA TOTEM POLE GATE DRIVER WITH UVLO PULL-DOWN AND VOLTAGE CLAMP
- DIP-8/SO-8 PACKAGES ECOPACK[®]

1.1 APPLICATIONS

- PFC PRE-REGULATORS FOR:
 - IEC61000-3-2 COMPLIANT SMPS (TV,

Figure 1. Packages

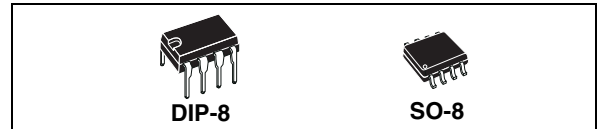


Table 1. Order Codes

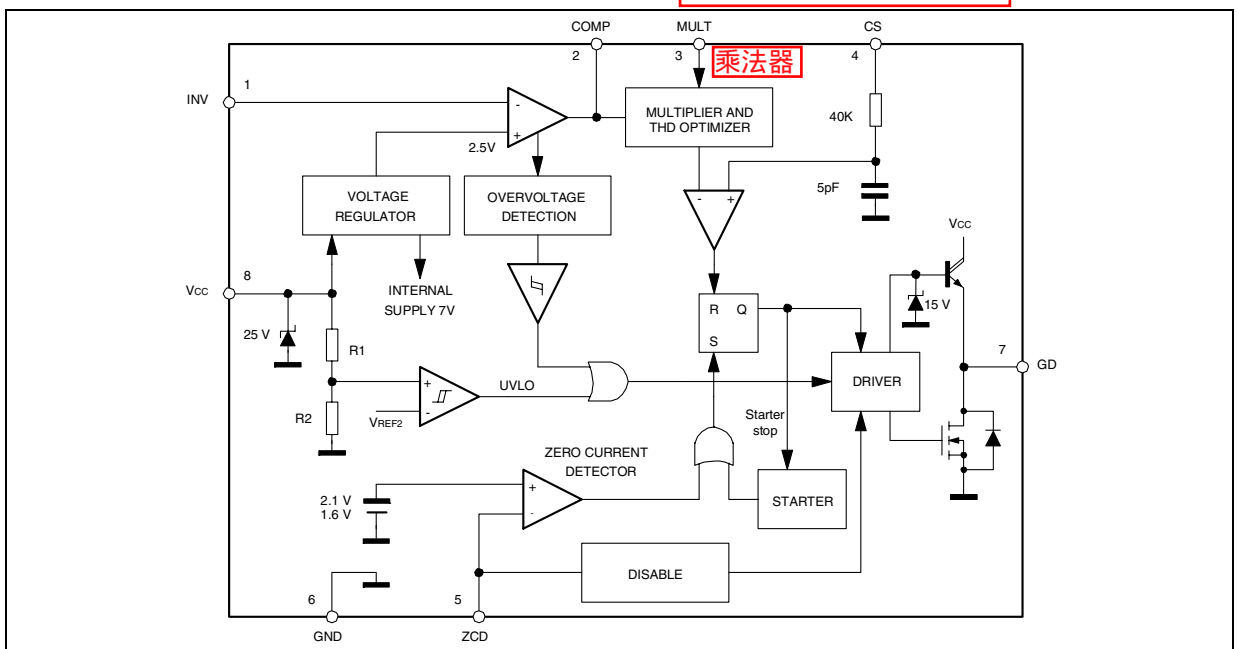
Part Number	Package
L6562N	DIP-8
L6562D	SO-8
L6562DTR	Tape & Reel

- DESKTOP PC, MONITOR) UP TO 300W
- HI-END AC-DC ADAPTER/CHARGER
- ENTRY LEVEL SERVER & WEB SERVER

2 Description

The L6562 is a current-mode PFC controller operating in Transition Mode (TM). Pin-to-pin compatible with the predecessor L6561, it offers improved performance.

Figure 2. Block Diagram



2 Description (continued)

The highly linear multiplier includes a special circuit, able to reduce AC input current distortion, that allows wide-range-mains operation with an extremely low THD, even over a large load range.

The output voltage is controlled by means of a voltage-mode error amplifier and a precise (1% @ $T_j = 25^\circ\text{C}$) internal voltage reference.

The device features extremely low consumption ($\leq 70 \mu\text{A}$ before start-up and $< 4 \text{ mA}$ running) and includes a disable function suitable for IC remote ON/OFF, which makes it easier to comply with energy saving norms (Blue Angel, EnergyStar, Energy2000, etc.).

An effective two-step OVP enables to safely handle overvoltages either occurring at start-up or resulting from load disconnection.

The totem-pole output stage, capable of 600 mA source and 800 mA sink current, is suitable for big MOS-FET or IGBT drive which, combined with the other features, makes the device an excellent low-cost solution for EN61000-3-2 compliant SMPS's up to 300W.

Table 2. Absolute Maximum Ratings

Symbol	Pin	Parameter	Value	Unit
V_{CC}	8	IC Supply voltage ($I_{CC} = 20 \text{ mA}$)	self-limited	V
---	1 to 4	Analog Inputs & Outputs	-0.3 to 8	V
I_{ZCD}	5	Zero Current Detector Max. Current	-50 (source) 10 (sink)	mA
P_{tot}		Power Dissipation @ $T_{amb} = 50^\circ\text{C}$ (DIP-8) (SO-8)	1 0.65	W
T_j		Junction Temperature Operating range	-40 to 150	$^\circ\text{C}$
T_{stg}		Storage Temperature	-55 to 150	$^\circ\text{C}$

Figure 3. Pin Connection (Top view)

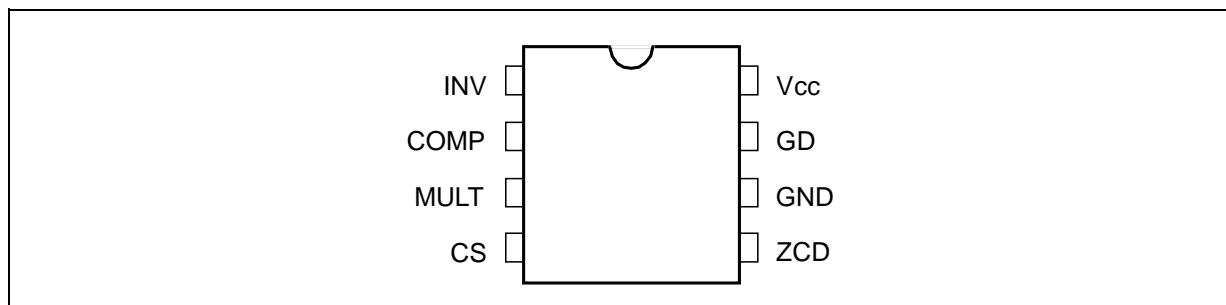


Table 3. Thermal Data

Symbol	Parameter	SO8	Minidip	Unit
$R_{th\ j-amb}$	Max. Thermal Resistance, Junction-to-ambient	150	100	$^\circ\text{C}/\text{W}$

Table 4. Pin Description

N°	Pin	Function
1	INV	Inverting input of the error amplifier. The information on the output voltage of the PFC pre-regulator is fed into the pin through a resistor divider.
2	COMP	Output of the error amplifier. A compensation network is placed between this pin and INV (pin #1) to achieve stability of the voltage control loop and ensure high power factor and low THD.
3	MULT	Main input to the multiplier. This pin is connected to the rectified mains voltage via a resistor divider and provides the sinusoidal reference to the current loop.
4	CS	Input to the PWM comparator. The current flowing in the MOSFET is sensed through a resistor, the resulting voltage is applied to this pin and compared with an internal sinusoidal-shaped reference, generated by the multiplier, to determine MOSFET's turn-off.
5	ZCD	Boost inductor's demagnetization sensing input for transition-mode operation. A negative-going edge triggers MOSFET's turn-on.
6	GND	Ground. Current return for both the signal part of the IC and the gate driver.
7	GD	Gate driver output. The totem pole output stage is able to drive power MOSFET's and IGBT's with a peak current of 600 mA source and 800 mA sink. The high-level voltage of this pin is clamped at about 12V to avoid excessive gate voltages in case the pin is supplied with a high V _{CC} .
8	V _{CC}	Supply Voltage of both the signal part of the IC and the gate driver. The supply voltage upper limit is extended to 22V min. to provide more headroom for supply voltage changes.

Table 5. Electrical Characteristics

(T_j = -25 to 125°C, V_{CC} = 12, C_O = 1 nF; unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
SUPPLY VOLTAGE						
V _{CC}	Operating range	After turn-on	10.3		22	V
V _{CCon}	Turn-on threshold	(1)	11	12	13	V
V _{CCOff}	Turn-off threshold	(1)	8.7	9.5	10.3	V
Hys	Hysteresis		2.2		2.8	V
V _Z	Zener Voltage	I _{CC} = 20 mA	22	25	28	V
SUPPLY CURRENT						
I _{start-up}	Start-up Current	Before turn-on, V _{CC} = 11V		40	70	μA
I _q	Quiescent Current	After turn-on		2.5	3.75	mA
I _{CC}	Operating Supply Current	@ 70 kHz		3.5	5	mA
I _q	Quiescent Current	During OVP (either static or dynamic) or V _{ZCD} = 150 mV			2.2	mA
MULTIPLIER INPUT						
I _{MULT}	Input Bias Current	V _{VFF} = 0 to 4 V			-1	μA
V _{MULT}	Linear Operation Range		0 to 3			V
$\frac{\Delta V_{CS}}{\Delta V_{MULT}}$	Output Max. Slope	V _{MULT} = 0 to 0.5V V _{COMP} = Upper clamp	1.65	1.9		V/V
K	Gain (2)	V _{MULT} = 1 V, V _{COMP} = 4 V	0.5	0.6	0.7	1/V
ERROR AMPLIFIER						
V _{INV}	Voltage Feedback Input Threshold	T _j = 25 °C	2.465	2.5	2.535	V
		10.3 V < V _{CC} < 22 V (1)	2.44		2.56	
	Line Regulation	V _{CC} = 10.3 V to 22V		2	5	mV
I _{INV}	Input Bias Current	V _{INV} = 0 to 3 V			-1	μA

Table 5. Electrical Characteristics (continued)(T_j = -25 to 125°C, V_{CC} = 12, C_O = 1 nF; unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
G _v	Voltage Gain	Open loop	60	80		dB
GB	Gain-Bandwidth Product			1		MHz
I _{COMP}	Source Current	V _{COMP} = 4V, V _{INV} = 2.4 V	-2	-3.5	-5	mA
	Sink Current	V _{COMP} = 4V, V _{INV} = 2.6 V	2.5	4.5		mA
V _{COMP}	Upper Clamp Voltage	I _{SOURCE} = 0.5 mA	5.3	5.7	6	V
	Lower Clamp Voltage	I _{SINK} = 0.5 mA ⁽¹⁾	2.1	2.25	2.4	V
CURRENT SENSE COMPARATOR						
I _{CS}	Input Bias Current	V _{CS} = 0			-1	μA
t _{d(H-L)}	Delay to Output			200	350	ns
V _{CS clamp}	Current sense reference clamp	V _{COMP} = Upper clamp	1.6	1.7	1.8	V
V _{CSoffset}	Current sense offset	V _{MULT} = 0		30		mV
		V _{MULT} = 2.5V		5		
ZERO CURRENT DETECTOR						
V _{ZCDH}	Upper Clamp Voltage	I _{ZCD} = 2.5 mA	5.0	5.7	6.5	V
V _{ZCDL}	Lower Clamp Voltage	I _{ZCD} = -2.5 mA	0.3	0.65	1	V
V _{ZCDA}	Arming Voltage (positive-going edge)	⁽³⁾		2.1		V
V _{ZCDT}	Triggering Voltage (negative-going edge)	⁽³⁾		1.6		V
I _{ZCDb}	Input Bias Current	V _{ZCD} = 1 to 4.5 V		2		μA
I _{ZCDsrc}	Source Current Capability		-2.5		-5.5	mA
I _{ZCDsnk}	Sink Current Capability		2.5			mA
V _{ZCDdis}	Disable threshold		150	200	250	mV
V _{ZCDen}	Restart threshold				350	mV
I _{ZCDres}	Restart Current after Disable		30	75		μA
STARTER						
t _{START}	Start Timer period		75	130	300	μs
OUTPUT OVERVOLTAGE						
I _{OVP}	Dynamic OVP triggering current		35	40	45	μA
H _{ys}	Hysteresis	⁽³⁾		30		μA
	Static OVP threshold	⁽¹⁾	2.1	2.25	2.4	V
GATE DRIVER						
V _{OH}	Dropout Voltage	I _{GDSOURCE} = 20 mA		2	2.6	
		I _{GDSOURCE} = 200 mA		2.5	3	V
V _{OL}		I _{GDSINK} = 200 mA		0.9	1.9	V
t _f	Voltage Fall Time			30	70	ns
t _r	Voltage Rise Time			40	80	ns
V _{Oclamp}	Output clamp voltage	I _{GDSOURCE} = 5mA; V _{CC} = 20V	10	12	15	V
	UVLO saturation	V _{CC} = 0 to V _{CCcon} , I _{sink} =10mA			1.1	V

(1) All parameters are in tracking

(2) The multiplier output is given by: V_{CS} = K · V_{MULT} · (V_{COMP} - 2.5)

(3) Parameters guaranteed by design, functionality tested in production.

3 Typical Electrical Characteristics

Figure 4. Supply current vs. Supply voltage

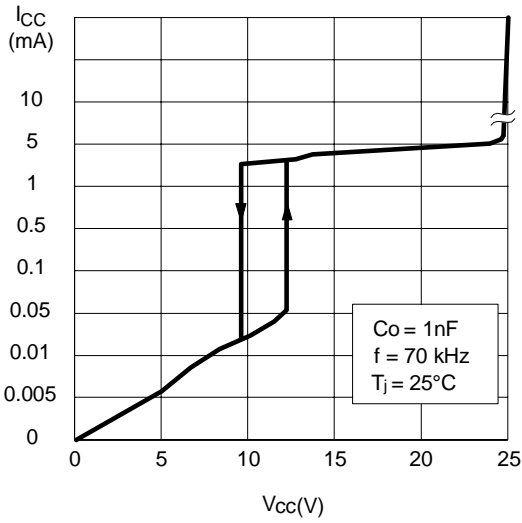


Figure 6. IC consumption vs. Tj

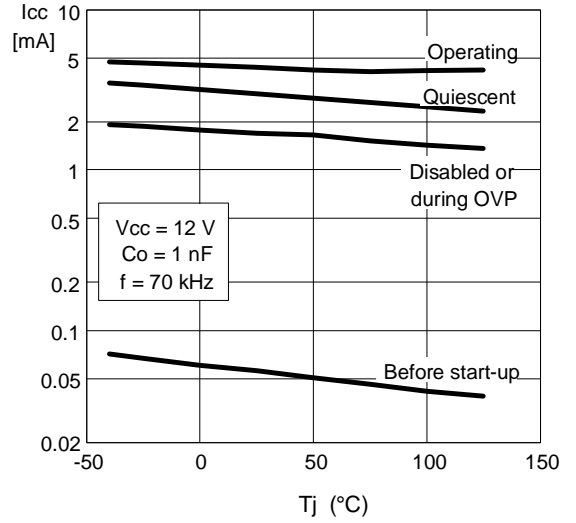


Figure 5. Start-up & UVLO vs. Tj

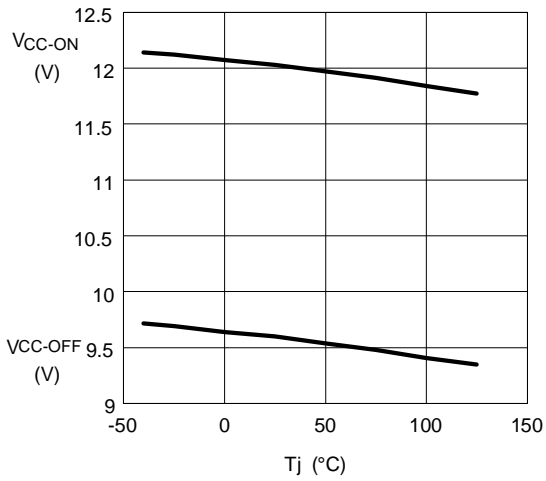


Figure 7. Vcc Zener voltage vs. Tj

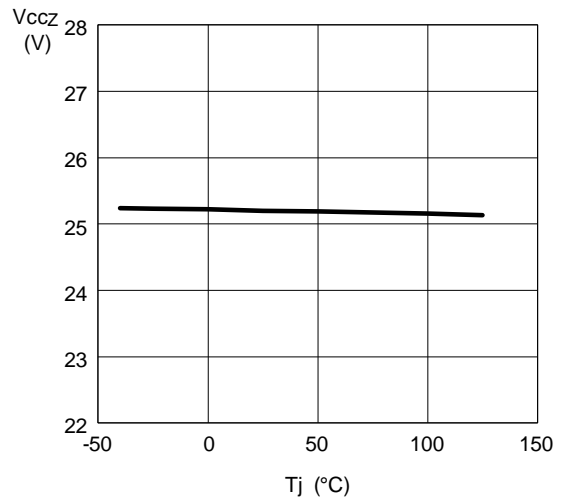


Figure 8. Feedback reference vs. T_j

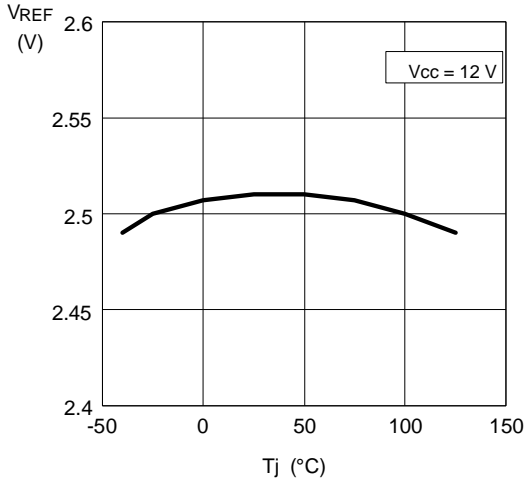


Figure 11. Delay-to-output vs. T_j

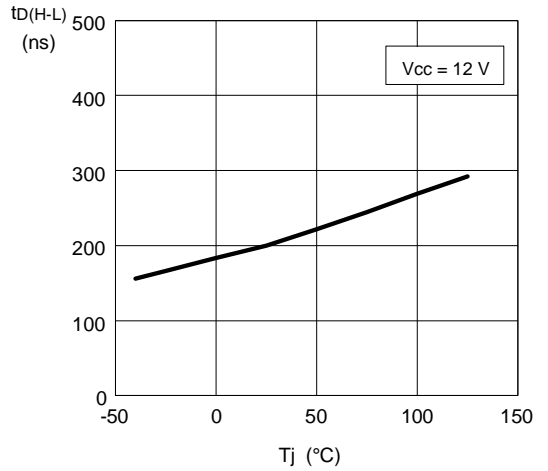


Figure 9. OVP current vs. T_j

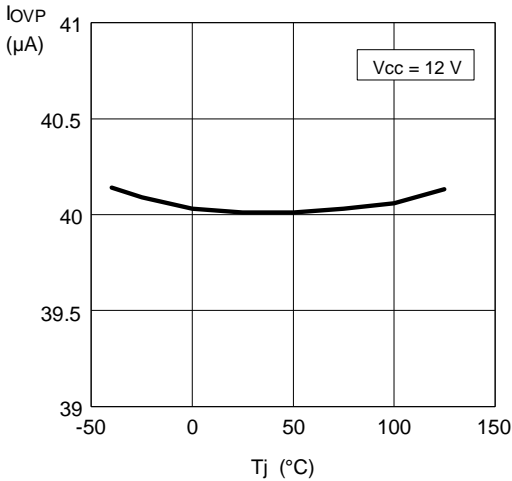


Figure 12. Multiplier characteristic

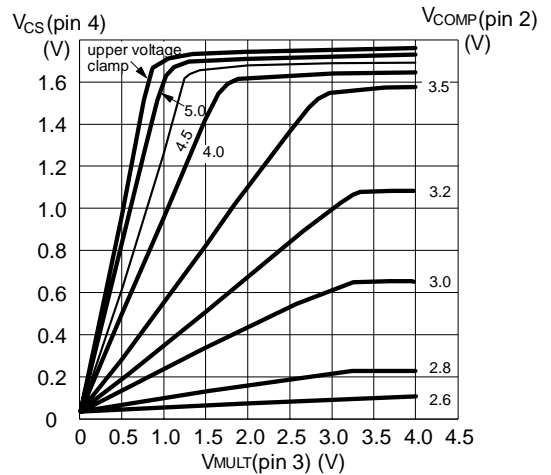


Figure 10. E/A output clamp levels vs. T_j

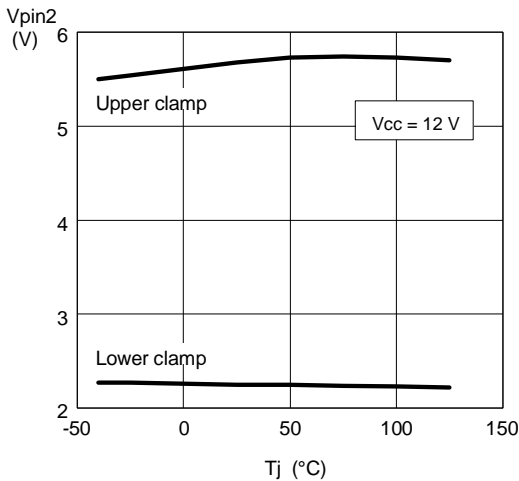


Figure 13. Multiplier gain vs. T_j

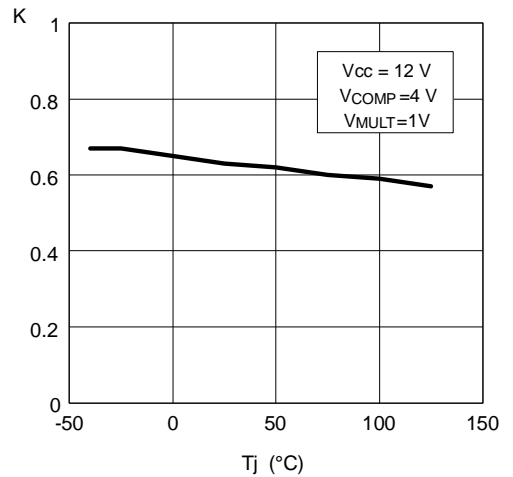


Figure 14. Vcs clamp vs. Tj

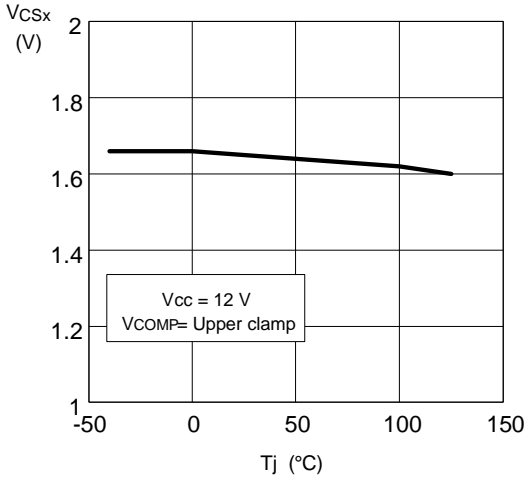


Figure 17. ZCD source capability vs. Tj

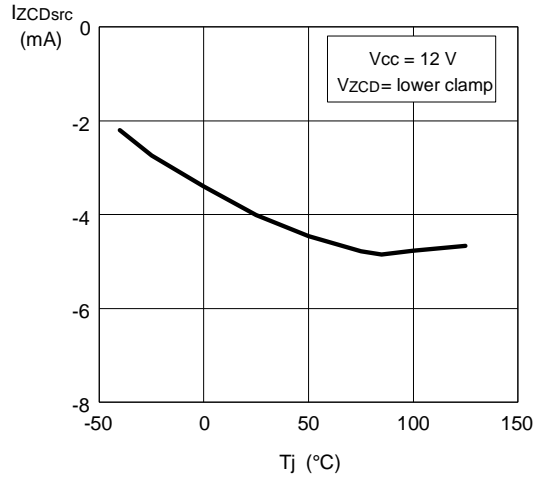


Figure 15. Start-up timer vs. Tj

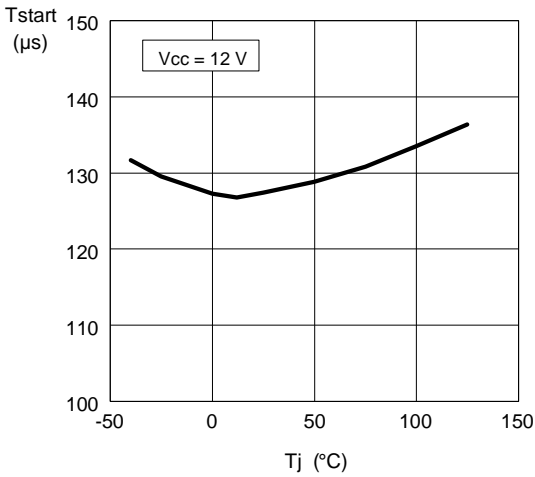


Figure 18. Gate-drive output low saturation

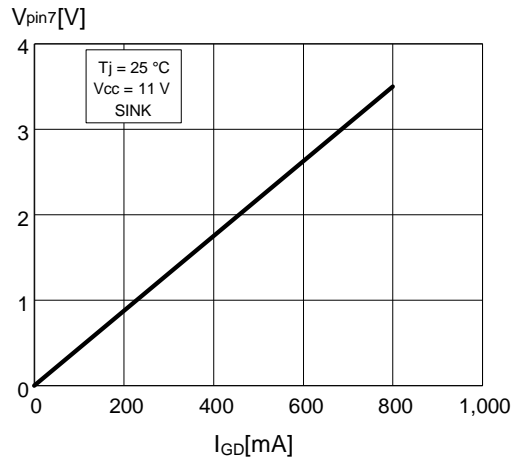


Figure 16. ZCD clamp levels vs. Tj

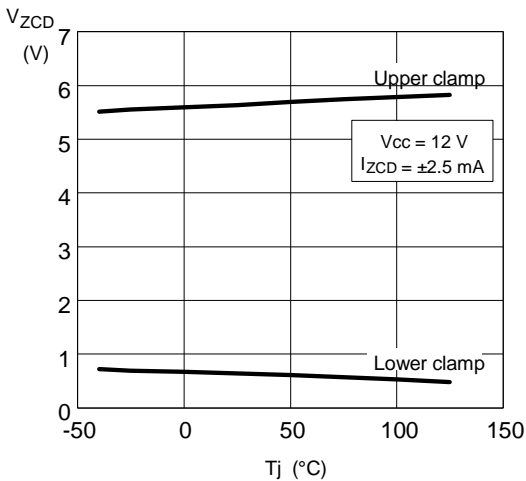


Figure 19. Gate-drive output high saturation

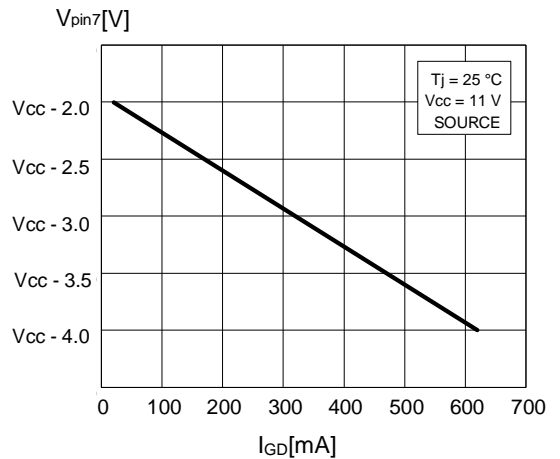
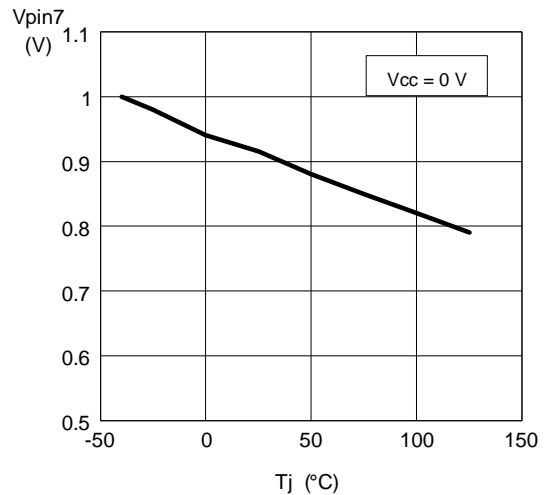


Figure 20. Gate-drive clamp vs. T_j Figure 21. UVLO saturation vs. T_j 

4 Application Information

4.1 Overvoltage protection

Under steady-state conditions, the voltage control loop keeps the output voltage V_o of a PFC pre-regulator close to its nominal value, set by the resistors R_1 and R_2 of the output divider. Neglecting ripple components, the current through R_1 , I_{R1} , equals that through R_2 , I_{R2} . Considering that the non-inverting input of the error amplifier is internally referenced at 2.5V, also the voltage at pin INV will be 2.5V, then:

$$I_{R2} = \frac{2.5}{R_2} = I_{R1} = \frac{V_o - 2.5}{R_1} .$$

If the output voltage experiences an abrupt change $\Delta V_o > 0$ due to a load drop, the voltage at pin INV will be kept at 2.5V by the local feedback of the error amplifier, a network connected between pins INV and COMP that introduces a long time constant to achieve high PF (this is why ΔV_o can be large). As a result, the current through R_2 will remain equal to $2.5/R_2$ but that through R_1 will become:

$$I'_{R1} = \frac{V_o - 2.5 + \Delta V_o}{R_1} .$$

The difference current $\Delta I_{R1} = I'_{R1} - I_{R2} = I'_{R1} - I_{R1} = \Delta V_o / R_1$ will flow through the compensation network and enter the error amplifier output (pin COMP). This current is monitored inside the L6562 and if it reaches about $37\ \mu\text{A}$ the output voltage of the multiplier is forced to decrease, thus smoothly reducing the energy delivered to the output. As the current exceeds $40\ \mu\text{A}$, the OVP is triggered (Dynamic OVP): the gate-drive is forced low to switch off the external power transistor and the IC put in an idle state. This condition is maintained until the current falls below approximately $10\ \mu\text{A}$, which re-enables the internal starter and allows switching to restart. The output ΔV_o that is able to trigger the Dynamic OVP function is then:

$$\Delta V_o = R_1 \cdot 40 \cdot 10^{-6} .$$

An important advantage of this technique is that the OV level can be set independently of the regulated output voltage: the latter depends on the ratio of R_1 to R_2 , the former on the individual value of R_1 . Another advantage is the precision: the tolerance of the detection current is 12%, that is 12% tolerance on ΔV_o . Since $\Delta V_o \ll V_o$, the tolerance on the absolute value will be proportionally reduced.

Example: $V_o = 400\text{ V}$, $\Delta V_o = 40\text{ V}$. Then: $R_1 = 40\text{V}/40\ \mu\text{A} = 1\text{M}\Omega$; $R_2 = 1\text{M}\Omega \cdot 2.5 / (400 - 2.5) = 6.289\text{k}\Omega$. The tolerance on the OVP level due to the L6562 will be $40 \cdot 0.12 = 4.8\text{V}$, that is 1.2% of the regulated value.

When the load of a PFC pre-regulator is very low, the output voltage tends to stay steadily above the nominal value, which cannot be handled by the Dynamic OVP. If this occurs, however, the error amplifier output will saturate low; hence, when this is detected, the external power transistor is switched off and the IC put in an idle state (Static OVP). Normal operation is resumed as the error amplifier goes back into its linear region. As a result, the L6562 will work in burst-mode, with a repetition rate that can be very low.

When either OVP is activated the quiescent consumption of the IC is reduced to minimize the discharge of the Vcc capacitor and increase the hold-up capability of the IC supply system.

4.2 THD optimizer circuit

The L6562 is equipped with a special circuit that reduces the conduction dead-angle occurring to the AC input current near the zero-crossings of the line voltage (crossover distortion). In this way the THD (Total Harmonic Distortion) of the current is considerably reduced.

A major cause of this distortion is the inability of the system to transfer energy effectively when the instantaneous line voltage is very low. This effect is magnified by the high-frequency filter capacitor placed after the bridge rectifier, which retains some residual voltage that causes the diodes of the bridge rectifier to be reverse-biased and the input current flow to temporarily stop.

Figure 22. THD optimization: standard TM PFC controller (left side) and L6562 (right side)



To overcome this issue the circuit embedded in the L6562 forces the PFC pre-regulator to process more energy near the line voltage zero-crossings as compared to that commanded by the control loop. This will result in both minimizing the time interval where energy transfer is lacking and fully discharging the high-frequency filter capacitor after the bridge. The effect of the circuit is shown in figure 23, where the key waveforms of a standard TM PFC controller are compared to those of the L6562.

Essentially, the circuit artificially increases the ON-time of the power switch with a positive offset added to

the output of the multiplier in the proximity of the line voltage zero-crossings. This offset is reduced as the instantaneous line voltage increases, so that it becomes negligible as the line voltage moves toward the top of the sinusoid.

To maximally benefit from the THD optimizer circuit, the high-frequency filter capacitor after the bridge rectifier should be minimized, compatibly with EMI filtering needs. A large capacitance, in fact, introduces a conduction dead-angle of the AC input current in itself - even with an ideal energy transfer by the PFC pre-regulator - thus making the action of the optimizer circuit little effective.

Figure 23. Typical application circuit (250W, Wide-range mains)



Figure 24. Demo board (EVAL6562-80W, Wide-range mains): Electrical schematic

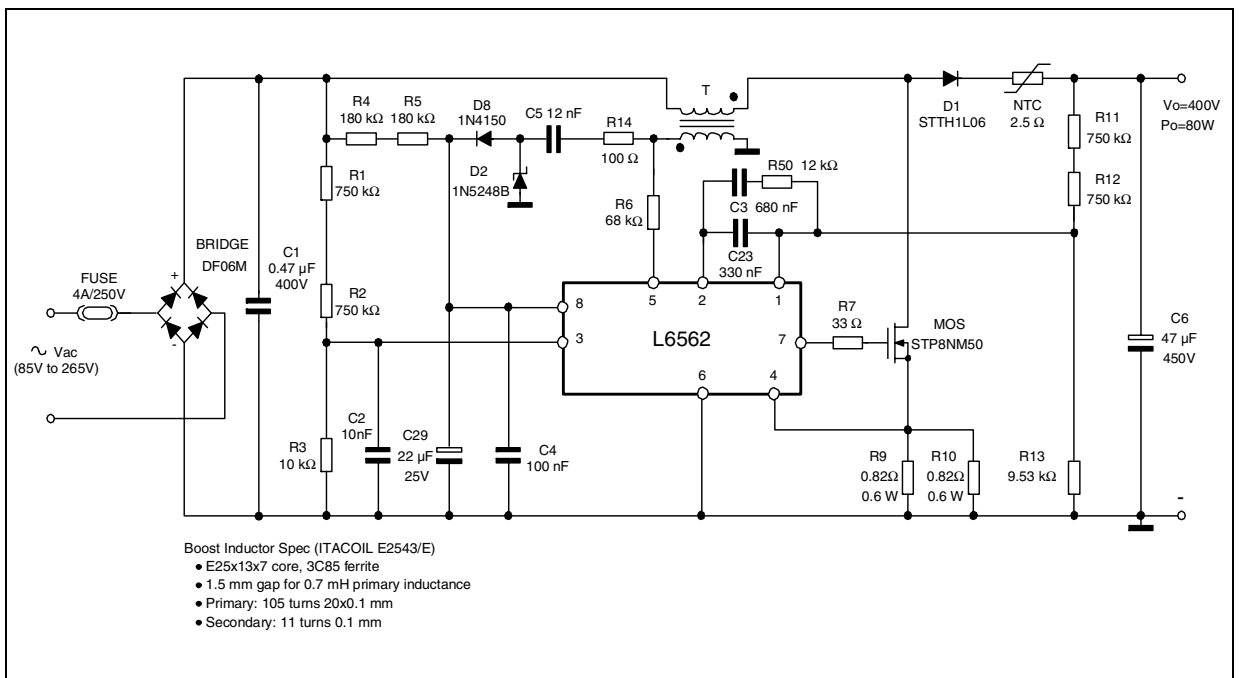


Table 8. EVAL6562N: No-load measurements

Vin (V _{AC})	Pin (W)	Vo (V _{DC})	ΔV_o (V _{pk-pk})	Po (W)
85	0.4	396.77	0.45	0
110	0.3	396.82	0.55	0
135	0.3	396.83	0.60	0
175 (*)	0.4	396.90	1.00	0
220 (*)	0.4	396.95	1.40	0
265 (*)	0.5	396.98	1.65	0

(*) V_{cc} = 12V supplied externally

Figure 26. Line filter (not tested for EMI compliance) used for EVAL6562N evaluation



5 Package Information

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark.

ECOPACK specifications are available at: www.st.com.

Figure 27. DIP-8 Mechanical Data & Package Dimensions

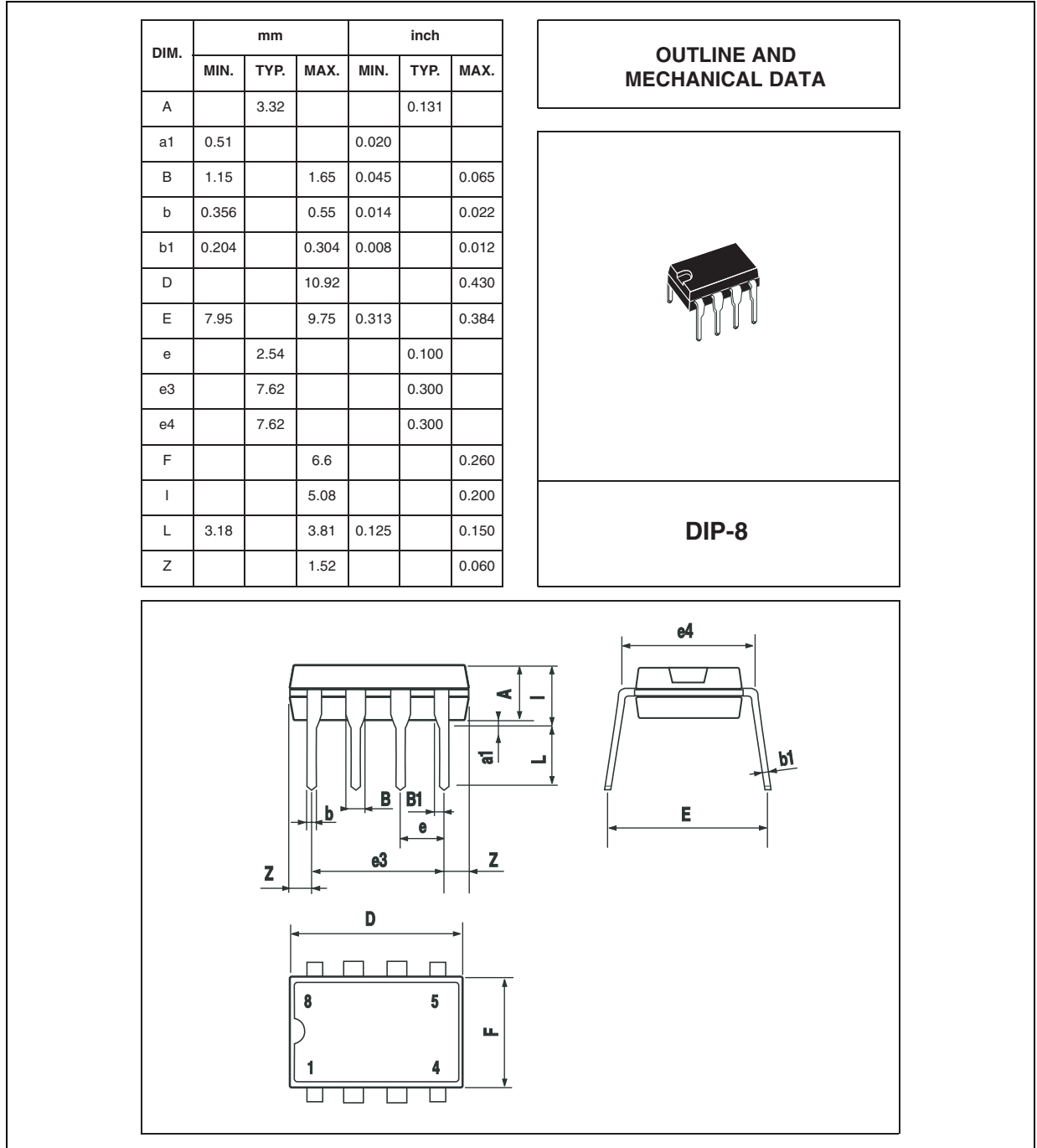
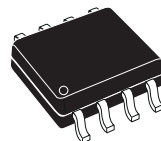


Figure 28. SO-8 Mechanical Data & Package Dimensions

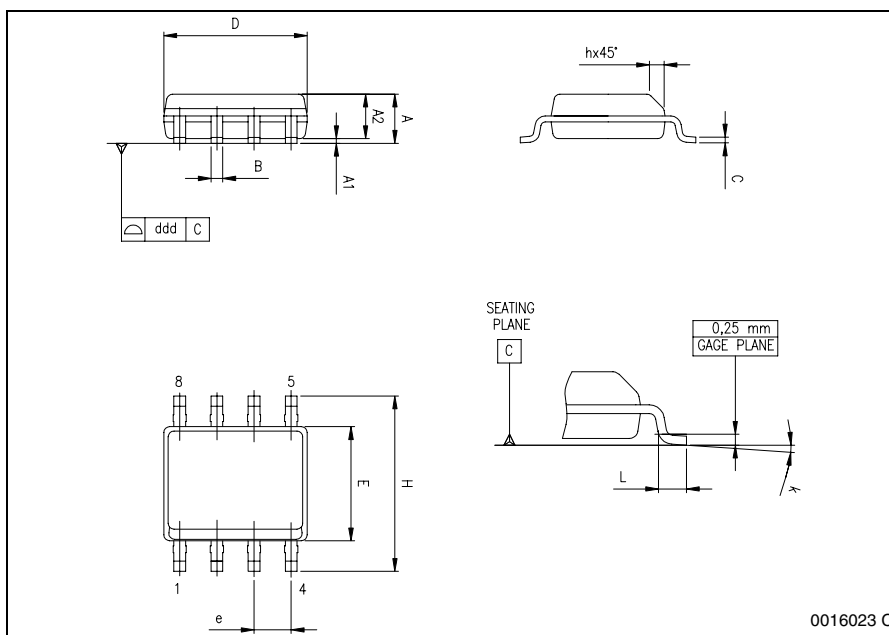
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.10		1.65	0.043		0.065
B	0.33		0.51	0.013		0.020
C	0.19		0.25	0.007		0.010
D (1)	4.80		5.00	0.189		0.197
E	3.80		4.00	0.15		0.157
e		1.27			0.050	
H	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	0° (min.), 8° (max.)					
ddd			0.10			0.004

Note: (1) Dimensions D does not include mold flash, protrusions or gate burrs.
Mold flash, protrusions or gate burrs shall not exceed 0.15mm (.006inch) in total (both side).

OUTLINE AND MECHANICAL DATA



SO-8



6 Revision History

Table 9. Revision History

Date	Revision	Description of Changes
January 2004	5	First Issue
June 2004	6	Modified the Style-look in compliance with the "Corporate Technical Publications Design Guide". Changed input of the power amplifier connected to Multiplier (Fig. 2).
May 2005	7	Modified Table 2: Absolute Maximim Ratings.
November 2005	8	Added in Section 5 the ECOPACK® certificate of conformity.

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics.
All other names are the property of their respective owners

© 2005 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -
Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com